

Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet

SPD65

Screening 2/

— = Not Screened

TX = TX Level

TXV = TXV

S = S Level

Package Type

— = Axial

SMS = Surface Mount Square Tab

Family/Voltage

54 = 800 V

55 = 1000 V

56 = 1200 V

57 = 1300 V

SPD6557 Series

6 AMPS 1300 VOLTS 5 μsec STANDARD RECOVERY RECTIFIER

FEATURES:

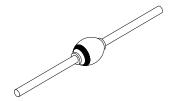
- Standard Recovery: 5 μsec maximum
- PIV up to 1500 Volts
- Low Reverse Leakage Current
- Hermetically Sealed
- Single Chip Construction
- High Voltage Replacement for 1N5553 &1N5554
- Low Thermal Resistance
- Available with 0.040" diameter leads
- TX, TXV, and Space Level Screening Available^{2/}
- Fast Recovery Versions Available. Contact Factory.
- For higher voltages-See SSDI p/n SDR6W

MAXIMUM RATINGS		Symbol	Value	Units
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SPD6557 SPD6556 SPD6555 SPD6554	$egin{array}{c} oldsymbol{V_{RRM}} \ oldsymbol{V_{R}} \end{array}$	1300 1200 1000 800	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T _A =2	5°C)	Io	6	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, Superimposed on I _O , allow junction to reach equilibrium between pulses, T _A =25°C)		I _{FSM}	150	Amps
Operating and Storage Temperature		T _{OP} & T _{stg}	-65 to +175	°C
Maximum Thermal Resistance Junction to Lead, L = 0.125" (Axial Lead) Junction to End Tab (Surface Mount		R _{eJL} R _{eJE}	8 4	°C/W

- 1/ For Ordering Information, Price, Operating Curves, and Availability- Contact Factory.
- 2/ Screening Based on MIL-PRF-19500. Screening Flow Available on Request.

Axial

Surface Mount Square Tab (SMS)



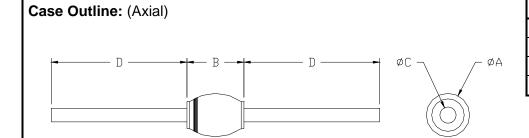






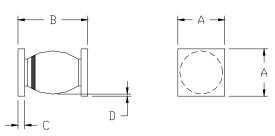
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ELECTRICAL CHARACTERISTICS		Symbol	Min	Max	Unit
Instantaneous Forward Voltage Drop (I _F = 6 Amps, T _A = 25°C, 300μsec Pulse)	$T_A = 25^{\circ}C$ $T_A = -55^{\circ}C$	V _{F1} V _{F2}		1.15 1.30	Volts Volts
Reverse Leakage Current (At Rated V _R , 300μsec pulse minimum)	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	I _{R1} I _{R2}	_ _	5.0 50	μ Α μ Α
Breakdown Voltage ($I_R = 50 \mu A, T_A = 25^{\circ}C$)	SPD6557 SPD6556 SPD6555 SPD6554	V _{BR}	1300 1200 1000 800		Volts
Junction Capacitance $(V_R = 10 V_{DC}, T_A = 25^{\circ}C, f = 1 MHz)$		CJ		50	pF
Reverse Recovery Time $(I_F = 500 \text{ mA}, I_R = 1 \text{ A}, I_{RR} = 250 \text{ mA}, T_A = 200 \text{ mA})$	25°C)	t _{rr}	_	5	μs



DIM	MIN	MAX
Α		0.215"
В	0.210"	0.300"
С	0.047"	0.053"
D	1.00"	





DIM	MIN	MAX
Α	0.195"	0.230"
В	0.260"	0.350"
С	0.020"	0.030"
D	0.002"	

Note: Dimensions prior to soldering.

NOTES:

Consult manufacturing for operating curves.

NOTE: All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.	DATA SHEET #: RC0086E	DOC
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